74AUP1G57

Low-power configurable multiple function gate

Rev. 10 — 21 January 2022

Product data sheet

1. General description

The 74AUP1G57 is a configurable multiple function gate with Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to V_{CC} or GND. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- · Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



Low-power configurable multiple function gate

3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G57GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2				
74AUP1G57GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP1G57GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74AUP1G57GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74AUP1G57GX	-40 °C to +125 °C	X2SON6	plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 × 0.8 × 0.32 mm	SOT1255-2				

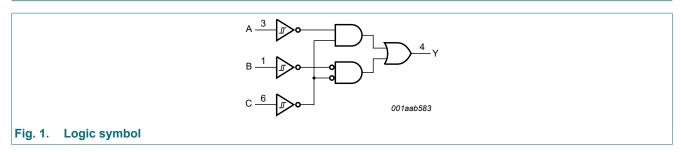
4. Marking

Table 2. Marking

Table 21 marking					
Marking code[1]					
aC					

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

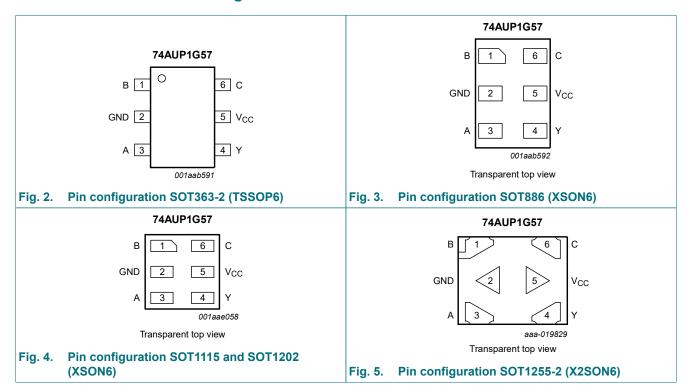
5. Functional diagram



Low-power configurable multiple function gate

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
Α	3	data input
Υ	4	data output
V _{CC}	5	supply voltage
С	6	data input

Low-power configurable multiple function gate

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input			Output
С	В	A	Υ
L	L	L	Н
L	L	Н	L
L	Н	L	Н
L	Н	Н	L
Н	L	L	L
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	Н

7.1. Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input AND	see Fig. 6
2-input AND with both inputs inverted	see Fig. 9
2-input NAND with inverted input	see Fig. 7 and Fig. 8
2-input OR with inverted input	see Fig. 7 and Fig. 8
2-input NOR	see Fig. 9
2-input NOR with both inputs inverted	see Fig. 6
2-input XNOR	see Fig. 10
Inverter	see Fig. 11
Buffer	see <u>Fig. 12</u>

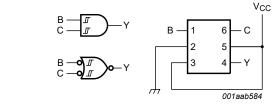


Fig. 6. 2-input AND gate or 2-input NOR gate with both inputs inverted

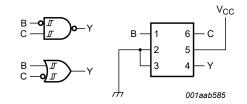


Fig. 7. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

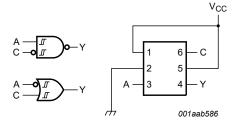


Fig. 8. 2-input NAND gate with input C inverted or 2-input OR gate with inverted A input

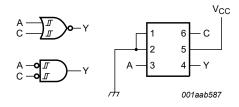
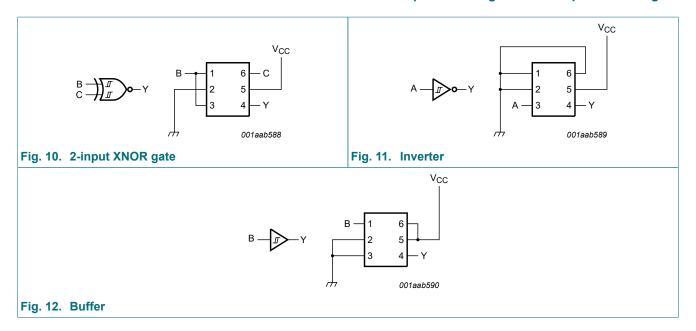


Fig. 9. 2-input NOR gate or 2-input AND gate with both inputs inverted

Low-power configurable multiple function gate



8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
lok	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: P_{tot} derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1255-2 (X2SON6) package: P_{tot} derates linearly with 3.3 mW/K above 75 °C.

^[2] For SOT363-2 (TSSOP6) package: P_{tot} derates linearly with 3.7 mW/K above 83 °C.

Low-power configurable multiple function gate

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C	1			1	
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	40	μA
Cı	input capacitance	$V_I = GND \text{ or } V_{CC}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	1.1	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 V$ to 3.6 V; $V_{CC} = 0 V$	-	-	±0.5	μA
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	50	μΑ
T _{amb} = -	40 °C to +125 °C					
V_{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V

Low-power configurable multiple function gate

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.75	μΑ
ΔI_{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	75	μΑ

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 14.

Symbol	Parameter	r Conditions		25 °C			-40 °C to +85 °C		-40 °C to +125 °C	
			Min	Typ[1]	Max	Min	Max	Min	Max	
$C_L = 5 p$	F									
t _{pd}	propagation delay	A, B and C to Y; [2] see Fig. 13								
		V _{CC} = 0.8 V	-	22.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.5	12.6	2.5	13.0	2.5	13.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	7.6	2.5	8.2	2.5	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.9	6.2	2.0	6.8	2.0	7.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.1	4.5	1.8	5.1	1.8	5.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	2.8	3.9	1.5	4.1	1.5	4.3	ns
C _L = 10	pF									
t _{pd}	propagation delay	A, B and C to Y; [2] see Fig. 13								
		V _{CC} = 0.8 V	-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.3	14.4	2.8	14.9	2.8	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	5.2	8.7	2.8	9.3	2.8	9.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.5	7.0	2.2	7.8	2.2	8.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	3.7	5.2	2.1	5.9	2.1	6.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.3	3.4	4.6	1.9	4.9	1.9	5.1	ns

Low-power configurable multiple function gate

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 15	pF							,		
	propagation delay	A, B and C to Y; [2] see Fig. 13								
		V _{CC} = 0.8 V	-	31.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.4	8.0	15.7	3.1	16.7	3.1	17.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.8	5.7	9.4	3.1	10.4	3.1	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	4.9	7.7	2.5	8.7	2.5	9.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.6	4.1	5.7	2.4	6.5	2.4	6.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.5	3.8	5.0	2.2	5.5	2.2	5.7	ns
C _L = 30	pF									
t _{pd}	propagation delay	A, B and C to Y; [2] see Fig. 13								
		V _{CC} = 0.8 V	-	37.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.6	10.4	20.9	3.9	21.8	3.9	22.3	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.4	12.2	3.8	13.4	3.8	14.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	6.2	9.9	3.1	11.1	3.1	11.8	ns
		V _{CC} = 2.3 V to 2.7 V	3.4	5.2	7.4	3.1	8.3	3.1	8.8	ns
		V _{CC} = 3.0 V to 3.6 V	3.2	4.9	6.6	2.8	7.0	2.8	7.4	ns
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF								
C _{PD}	power dissipation	f_i = 1 MHz; [3][4] V _I = GND to V _{CC}								
	capacitance	V _{CC} = 0.8 V	-	2.6	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.1	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.7	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.3	-	-	-	-	-	pF

- All typical values are measured at nominal V_{CC}.
- t_{pd} is the same as t_{PLH} and t_{PHL} .

 All specified values are the average typical values over all stated loads. [3]
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where: f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Low-power configurable multiple function gate

11.1. Waveforms and test circuit

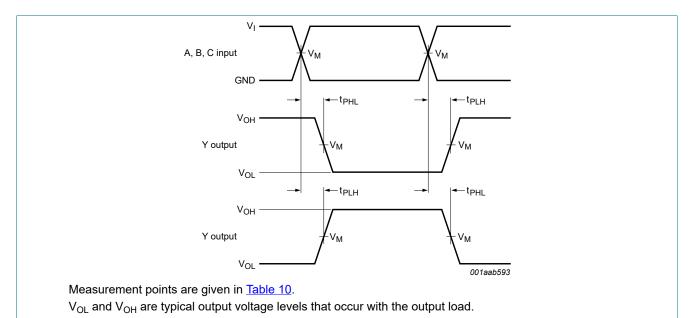
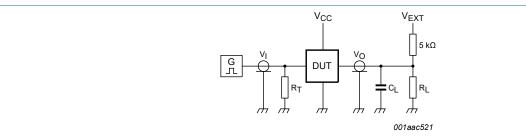


Table 10. Measurement points

Supply voltage	Output	Input				
V _{CC}	V _M	V _M	VI	$t_r = t_f$		
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns		



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 13. Input A, B and C to output Y propagation delay times

Fig. 14. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times, R_{L} = 5 $k\Omega_{\cdot}$

For measuring propagation delays, set-up and hold times, and pulse width, R_L = 1 $M\Omega$.

Low-power configurable multiple function gate

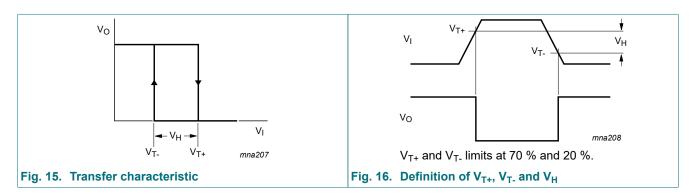
11.2. Transfer characteristics

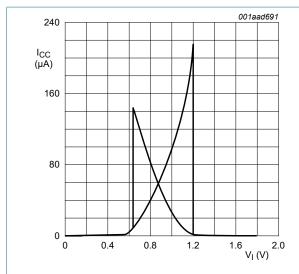
Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 14.

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
thre	positive-going	see Fig. 15 and Fig. 16								
	threshold voltage	V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	Voltage	V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V _{T-}	negative-going	see <u>Fig. 15</u> and <u>Fig. 16</u>								
	threshold voltage	V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
	Voltage	V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 15</u> , <u>Fig. 16</u> , <u>Fig. 17</u> and <u>Fig. 18</u>								
		V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

11.3. Waveform transfer characteristics







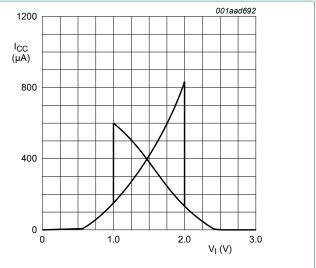


Fig. 18. Typical transfer characteristics; V_{CC} = 3.0 V

Low-power configurable multiple function gate

12. Package outline

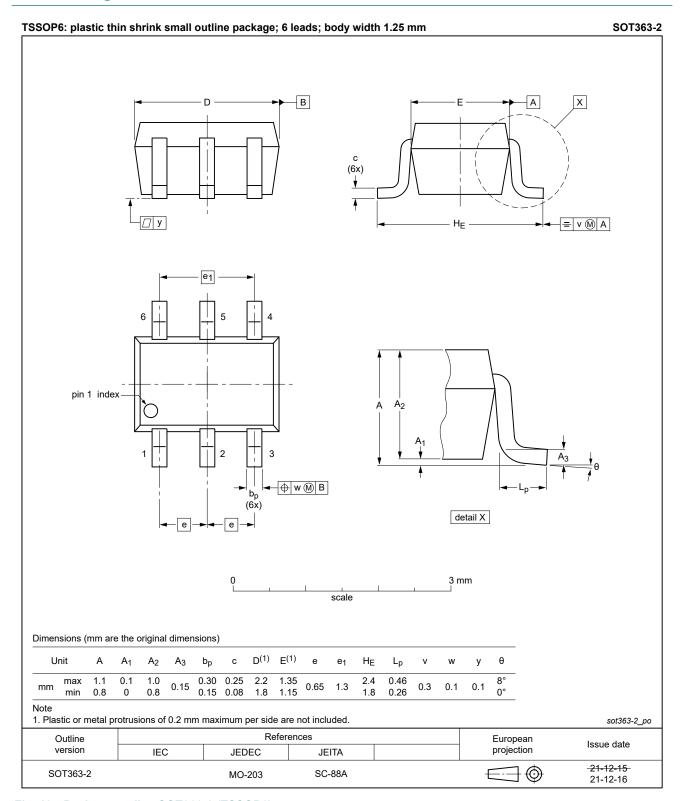


Fig. 19. Package outline SOT363-2 (TSSOP6)

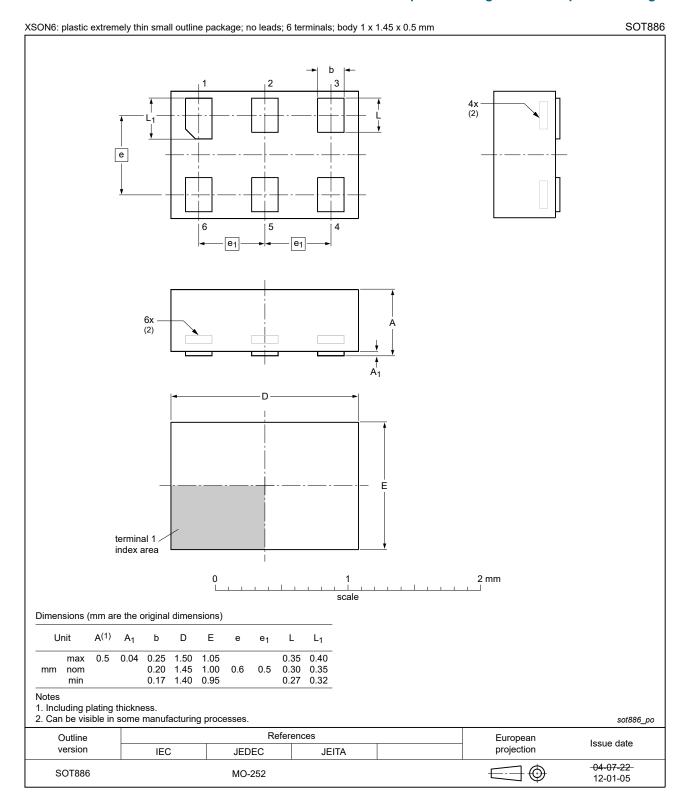


Fig. 20. Package outline SOT886 (XSON6)

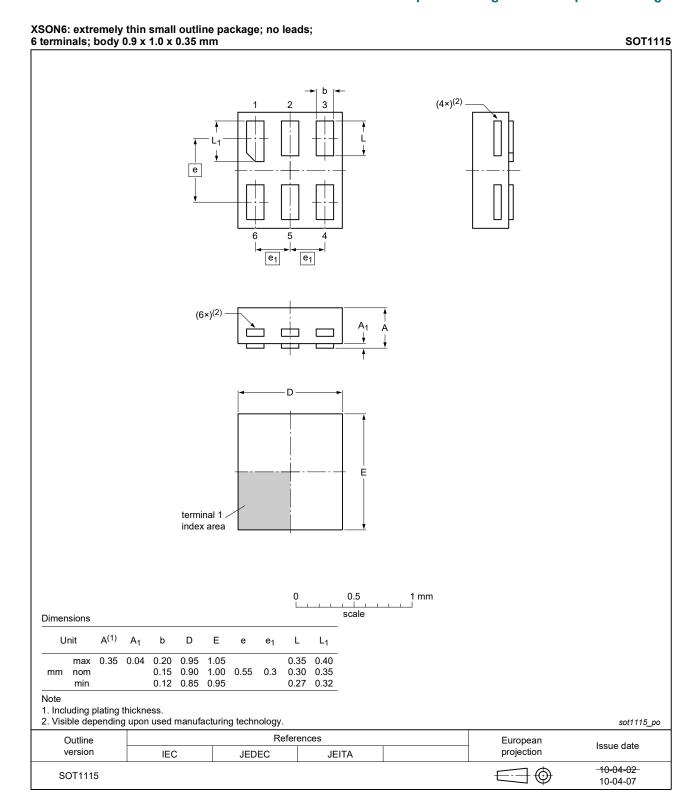


Fig. 21. Package outline SOT1115 (XSON6)

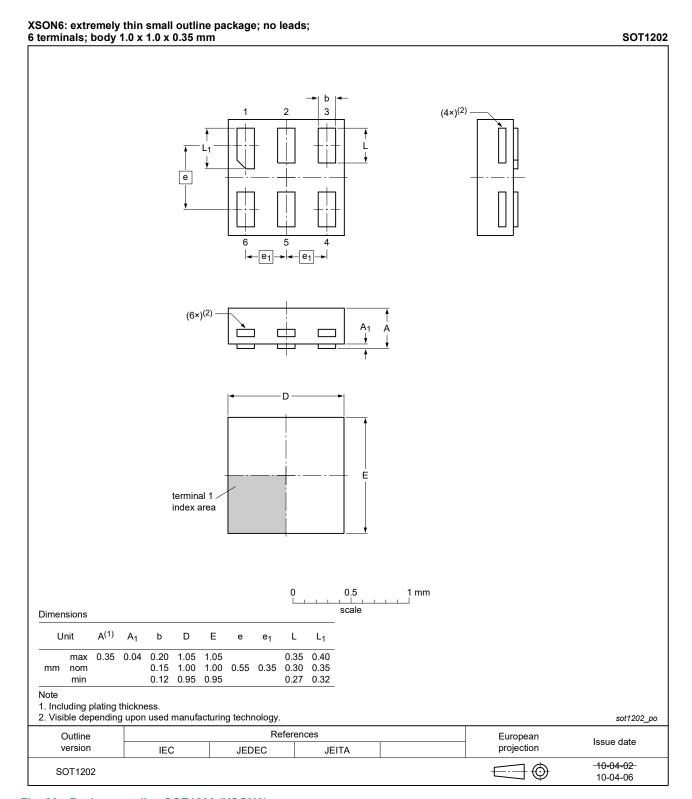


Fig. 22. Package outline SOT1202 (XSON6)

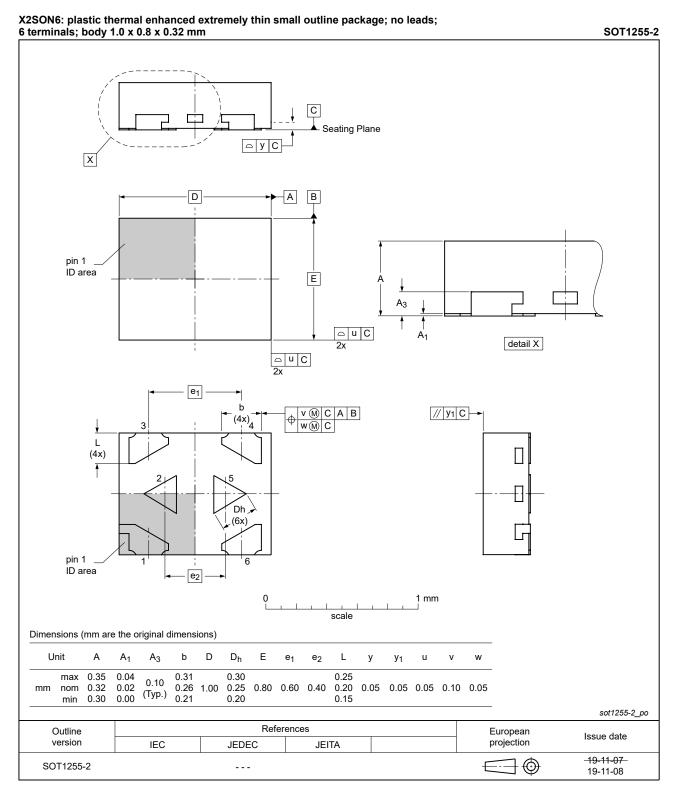


Fig. 23. Package outline SOT1255-2 (X2SON6)

Low-power configurable multiple function gate

13. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AUP1G57 v.10	20220121	Product data sheet	-	74AUP1G57 v.9				
Modifications:	Package Se	Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6).						
74AUP1G57 v.9	20211104	Product data sheet	-	74AUP1G57 v.8				
Modifications:	<u>Table 6</u>: DeType numb	 Section 1 and Section 2 updated. Table 6: Derating values for P_{tot} total power dissipation updated. Type number 74AUP1G57GF (SOT891/XSON6) removed. SOT1255 (X2SON6) package changed to SOT1255-2 (X2SON6) package. 						
74AUP1G57 v.8	20180223	Product data sheet	-	74AUP1G57 v.7				
Modifications:	guidelines	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 						
74AUP1G57 v.7	20150916	Product data sheet	-	74AUP1G57 v.6				
Modifications:	Added type	Added type number 74AUP1G57GX (SOT1255/X2SON6).						
74AUP1G57 v.6	20120815	Product data sheet	-	74AUP1G57 v.5				
Modifications:	• Package ou	Package outline drawing of SOT886 (Fig. 20) modified.						
74AUP1G57 v.5	20111125	Product data sheet	-	74AUP1G57 v.4				
74AUP1G57 v.4	20100720	Product data sheet	-	74AUP1G57 v.3				
74AUP1G57 v.3	20090622	Product data sheet	-	74AUP1G57 v.2				
74AUP1G57 v.2	20090323	Product data sheet	-	74AUP1G57 v.1				
74AUP1G57 v.1	20061123	Product data sheet	-	-				

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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Low-power configurable multiple function gate

Contents

1. General description	1
2. Features and benefits	1
3. Ordering information	2
4. Marking	2
5. Functional diagram	2
6. Pinning information	3
6.1. Pinning	3
6.2. Pin description	3
7. Functional description	4
7.1. Logic configurations	4
8. Limiting values	5
9. Recommended operating conditions	6
10. Static characteristics	6
11. Dynamic characteristics	8
11.1. Waveforms and test circuit	10
11.2. Transfer characteristics	11
11.3. Waveform transfer characteristics	11
12. Package outline	13
13. Abbreviations	18
14. Revision history	18
15. Legal information	19

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